TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

## 2SK30ATM

Low Noise Pre-Amplifier, Tone Control Amplifier and DC-AC High Input Impedance Amplifier Circuit Applications

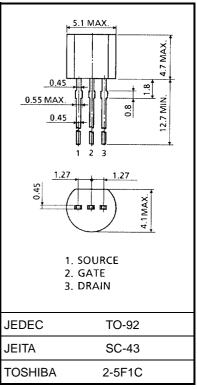
- High breakdown voltage:  $V_{GDS} = -50 \text{ V}$
- High input impedance:  $I_{GSS} = -1 \text{ nA (max) (V}_{GS} = -30 \text{ V)}$
- Low noise: NF = 0.5dB (typ.)

 $(V_{DS} = 15 \text{ V}, V_{GS} = 0, R_G = 100 \text{ k}\Omega, f = 120 \text{ Hz})$ 

## **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	$V_{GDS}$	-50	V
Gate current	IG	10	mA
Drain power dissipation	P <sub>D</sub>	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

Unit: mm

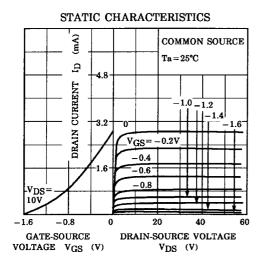


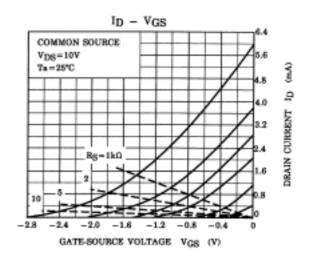
Weight: 0.21 g (typ.)

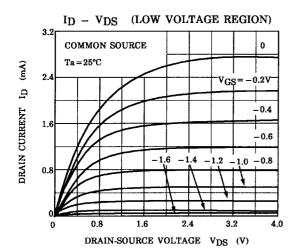
## **Electrical Characteristics (Ta = 25°C)**

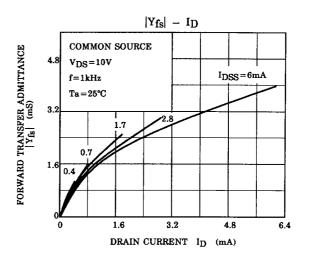
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I <sub>GSS</sub>	$V_{GS} = -30 \text{ V}, V_{DS} = 0$	_	_	-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0$ , $I_G = -100 \mu A$	-50	_	_	V
Drain current	I <sub>DSS</sub> (Note)	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0	0.3	_	6.5	mA
Gate-source cut-off voltage	V <sub>GS (OFF)</sub>	$V_{DS} = 10 \text{ V}, I_D = 0.1 \mu A$	-0.4	_	-5.0	٧
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$	1.2	_	_	mS
Input capacitance	C <sub>iss</sub>	$V_{GS} = 0, V_{DS} = 0, f = 1 \text{ MHz}$	_	8.2	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	$V_{GD} = -10 \text{ V}, V_{DS} = 0, f = 1 \text{ MHz}$	_	2.6	_	pF
Noise figure	NF	$V_{DS} = 15 \text{ V}, V_{GS} = 0$ $R_G = 100 \text{ k}\Omega, f = 120 \text{ Hz}$	_	0.5	5.0	dB

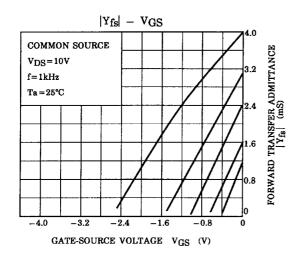
Note: I<sub>DSS</sub> classification R: 0.30~0.75, O: 0.60~1.40, Y: 1.20~3.00, GR: 2.60~6.50

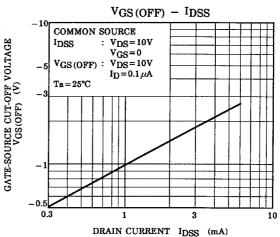




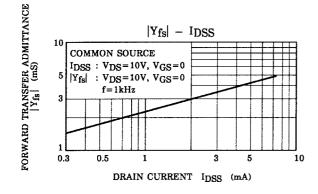


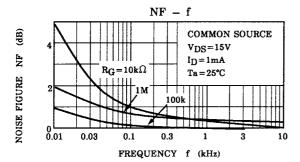


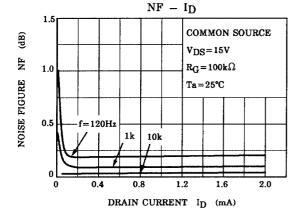


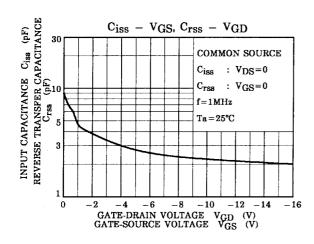


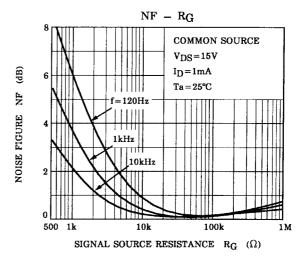
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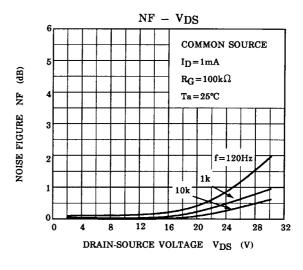


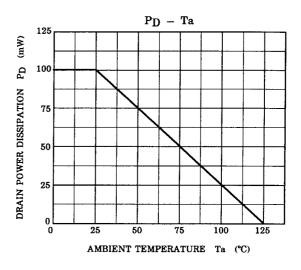












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